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High voltage fast-switching NPN power transistor

Preliminary data

Features

- High voltage capability
- Low spread of dynamic parameters
- Very high switching speed

Applications

- Switching mode power supplies

Description

The device is manufactured using high voltage Multi Epitaxial Planar technology for high switching speeds and high voltage capability. It uses a Hollow Emitter structure to enhance switching speeds.

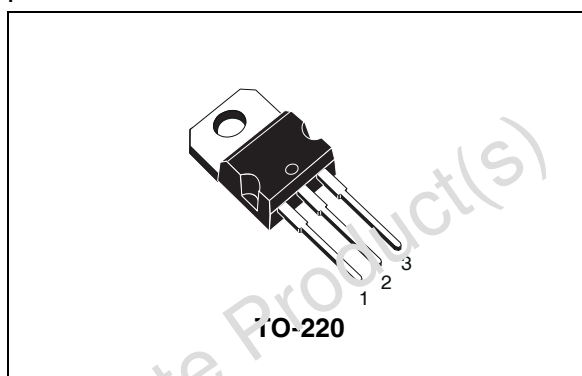


Figure 1. Internal schematic diagram

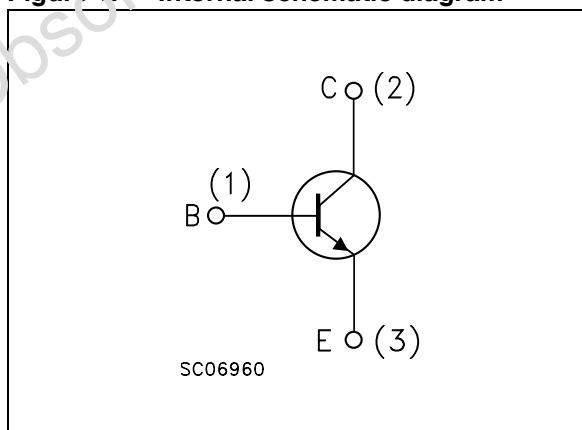


Table 1. Device summary

Order code	Marking	Package	Packaging
STH13009	H13009	TO-220	Tube

1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CEV}	Collector-emitter voltage ($V_{BE} = -1.5V$)	700	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	400	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	12	V
I_C	Collector current	12	A
I_{CM}	Collector peak current ($t_p < ms$)	24	A
I_B	Base current	6	A
I_{BM}	Base peak current ($t_p < ms$)	12	A
P_{TOT}	Total dissipation at $T_{case} = 25^{\circ}C$	100	W
T_{stg}	Storage temperature	-65 to 150	$^{\circ}C$
T_J	Max. operating junction temperature	150	$^{\circ}C$

Table 3. Thermal data

Symbol	Parameters	Value	Unit
$R_{thj-case}$	Thermal resistance junction case max	1.25	$^{\circ}C/W$

2 Electrical characteristics

($T_{case} = 25^{\circ}C$; unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CEV}	Collector cut-off current ($V_{BE} = -1.5V$)	$V_{CE} = 700 V$			10	μA
		$V_{CE} = 700 V \quad T_C = 100^{\circ}C$			500	μA
I_{EBO}	Emitter cut-off current ($I_C = 0$)	$V_{EB} = 10 V$			10	μA
$V_{CEO(sus)}^{(1)}$	Collector-emitter sustaining voltage ($I_B = 0$)	$I_C = 10 mA$	400			V
$V_{CE(sat)}^{(1)}$	Collector-emitter saturation voltage	$I_C = 4 A \quad I_B = 0.8 A$		0.2	0.5	V
		$I_C = 5 A \quad I_B = 1 A$		0.25	0.6	V
		$I_C = 8 A \quad I_B = 1.6 A$		0.35	1	V
		$I_C = 12 A \quad I_B = 2.4 A$		0.6	2	V
$V_{BE(sat)}^{(1)}$	Base-emitter saturation voltage	$I_C = 5 A \quad I_B = 1 A$			1.2	V
		$I_C = 8 A \quad I_B = 1.6 A$			1.6	V
$h_{FE}^{(1)}$	DC current gain	$I_C = 5 A \quad V_{CE} = 5 V$	18		30	
		$I_C = 8 A \quad V_{CE} = 5 V$	11		23	
t_s t_f	Inductive load Storage time Fall time	$V_{CC} = 250 V \quad I_C = 5 A$				
		$I_{B1} = 1 A \quad I_{B2} = -2 A$ $L = 200 \mu H$			1.7	2.5
				100	140	ns

1. Pulsed duration = 300 ms, duty cycle $\geq 1.5\%$.

2.1 Electrical characteristic (curves)

Figure 2. Safe operating area

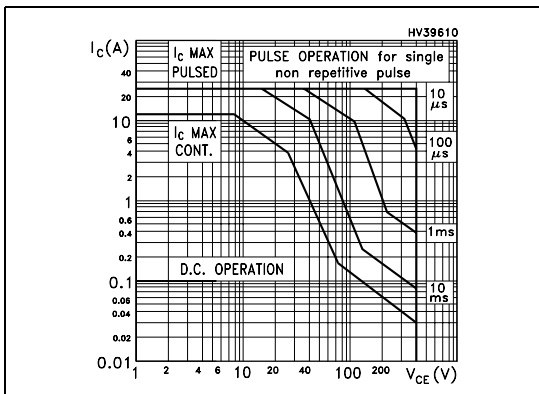


Figure 3. Derating curve

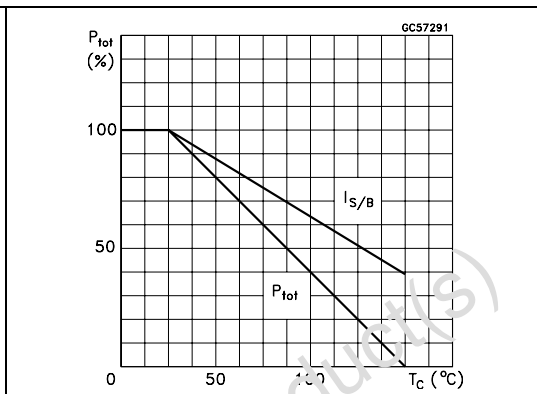


Figure 4. DC current gain

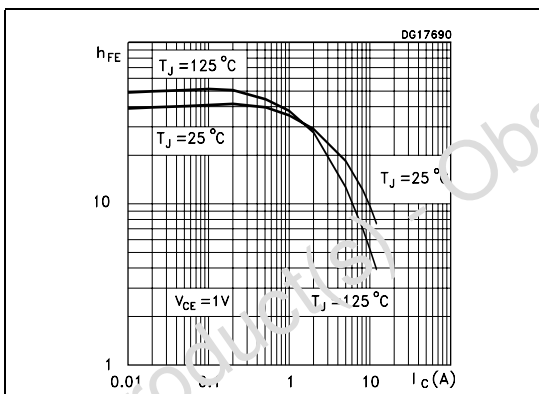


Figure 5. DC current gain

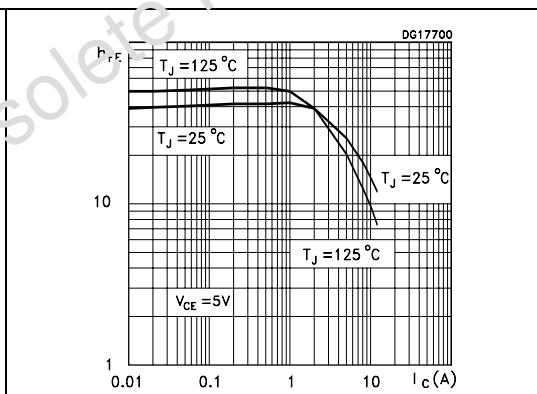


Figure 6. Collector-emitter saturation voltage

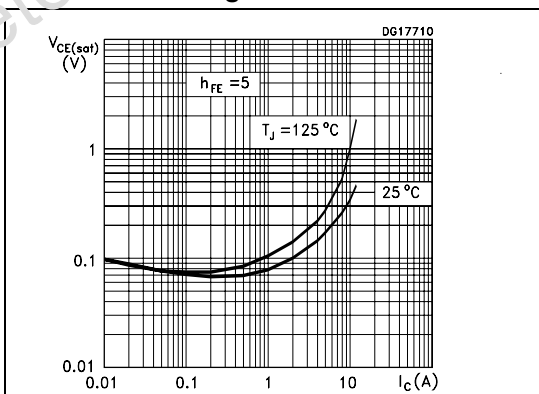


Figure 7. Base-emitter saturation voltage

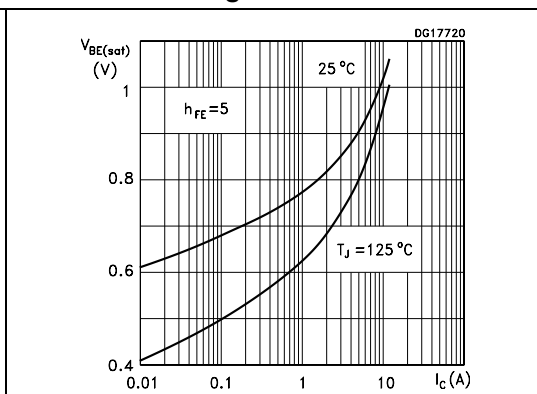
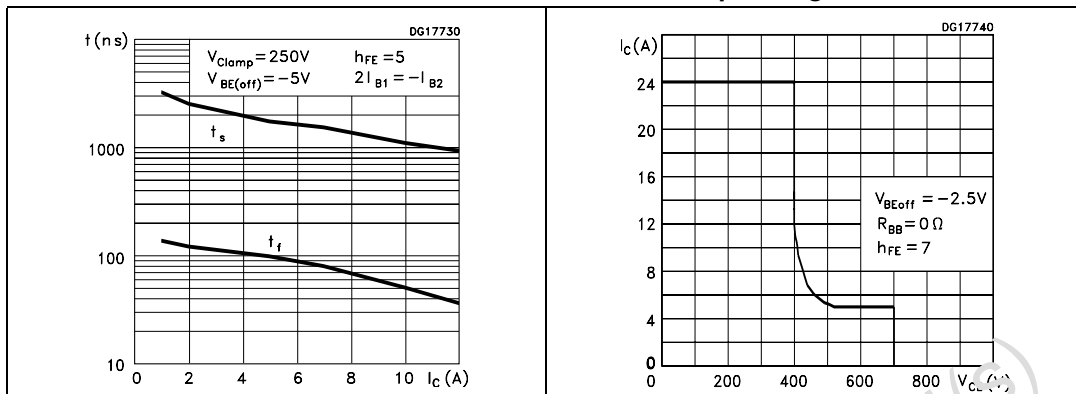
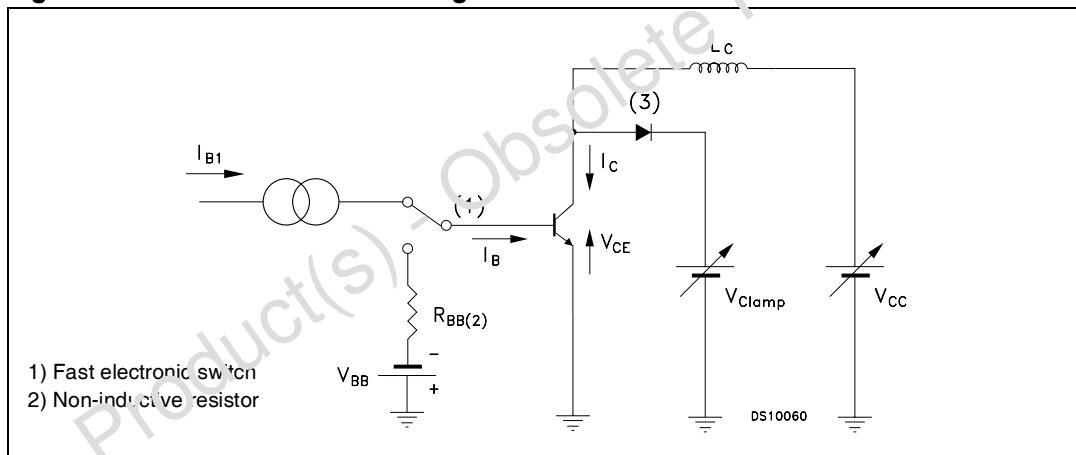


Figure 8. Inductive load switching time **Figure 9. Reverse biased safe operating area**



2.2 Test circuit

Figure 10. Inductive load switching test circuit



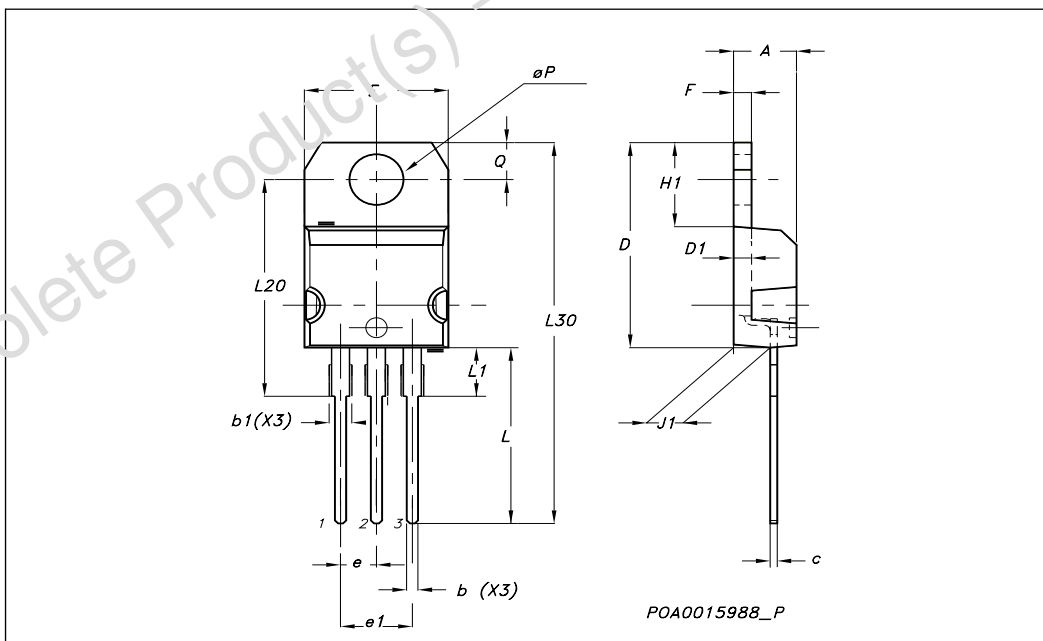
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

Obsolete Product(s) - Obsolete Product(s)

TO-220 Mechanical data

DIM.	mm.		
	MIN.	TYP	MAX.
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
c	0.49		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
e	2.40		2.70
e1	4.95		5.1
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
øP	3.75		3.85
Q	2.65		2.95



4 Revision history

Table 5. Document revision history

Date	Revision	Changes
15-Oct-2007	1	Initial Release

Obsolete Product(s) - Obsolete Product(s)

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